

# Windowless - Large Area APDs

## Electro-Optical Characteristics All specifications apply when APD is operated at 23°C and at a gain of 200.



Active Area Diameter	Bias Voltage Range†	Temperature Coefficient of Breakdown	Capacitance f = 100kHz	Dark Current		Noise Current Spectral Density f = 100kHz		Rise Time $\lambda = 675 \text{ nm}$ Load = $50\Omega$	
		Voltage	Тур	Тур	Max	Тур	Max	Тур	Max
(mm)	(V)	(%/°C)	(pF)	(nA)	(nA)	(pA/√Hz)	(pA/√Hz)	(ns)	(ns)
3	1700 to 2000	+0.1	15	20	60	0.7	1.4	8	12
5			25	35	100	1.0	2.0	10	15
10			65	90	230	1.5	3.0	12	18
16			130	280	600	2.5	5.5	15	22



5 mm

#### Active Area Spectral Responsivity Number Diameter Enhancement **Typical** (A/W) (mm) 118-70-75-520 DUV 30 @ 160nm 38 @ 350nm 118-70-73-520 UV 3 118-70-74-520 70 @ 500nm Blue 100 @ 750nm 118-70-72-520 Red/IR 197-70-75-520 30 @ 160nm DUV 38 @ 350nm 197-70-73-520 UV 5 70 @ 500nm 197-70-74-520 Blue 197-70-72-520 100 @ 750nm Red/IR 394-70-75-5X0‡ 30 @ 160nm DUV 38 @ 350nm 394-70-73-5X0‡ UV 10 394-70-74-5X0‡ 70 @ 500nm Blue 100 @ 750nm 394-70-72-5X0‡ Red/IR 30 @ 160nm 630-70-75-5X0‡ DUV 630-70-73-5X0‡ UV 38 @ 350nm 16 630-70-74-5X0‡ Blue 70 @ 500nm 630-70-72-5X0‡ 100 @ 750nm Red/IR

#### Absolute Maximum Ratingso

Gain, M @ λ=675nm	250		
Operating Temp Range (°C)	-55 to +40		
Storage Temp Range (°C)	-55 to +70		
Power Dissipation @23°C (W)	3mm - 0.12 5mm - 0.2 10mm - 0.4 16mm - 0.6		



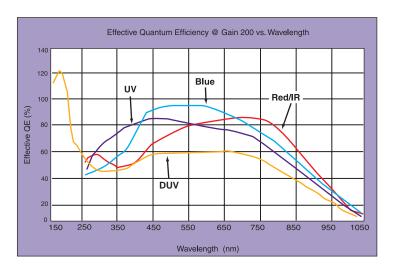
10 mm

- † Positive high voltage (HV) is applied to the cathode contact. The maximum value for the operating HV is specified with each device.
- † "X" indicates package style; "0" = SHV connector (supplied with mating connector) and "1" = a single pin connection.

  Operating beyond these limits may cause permanent damage to the device.

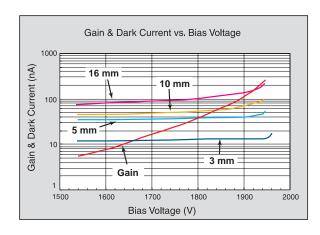


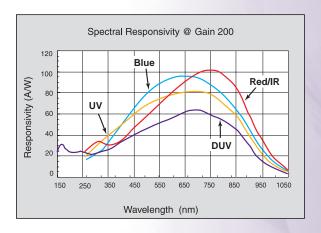
16 mm

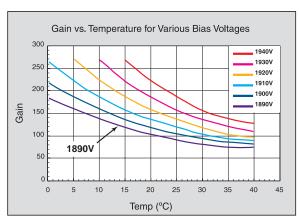


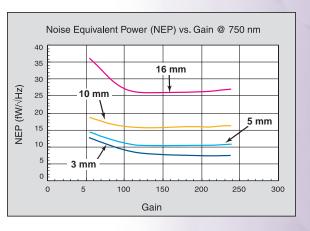
### Typical Performance Graphs



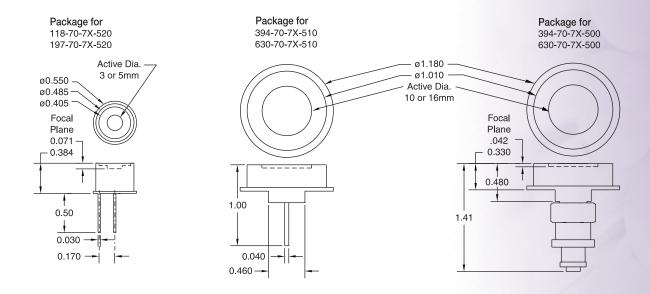








### Mechanical Dimensions



Center pin on all three package types is the APD's cathode and case is the APD's anode.